

# isc Silicon NPN Darlington Power Transistor

# **TIP141F**

## **DESCRIPTION**

- · High DC Current Gain-
- : h<sub>FE</sub> = 1000(Min)@ I<sub>C</sub>= 5A
- · Collector-Emitter Sustaining Voltage-
  - :  $V_{CEO(SUS)} = 80V(Min)$
- Complement to Type TIP146F
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

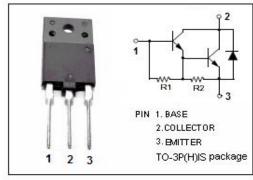


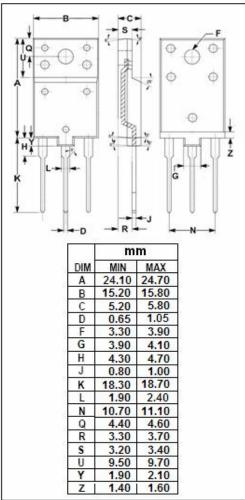
## **APPLICATIONS**

 Designed for general purpose amplifier and low frequency switching applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	80	V
Vceo	Collector-Emitter Voltage	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	10	Α
Ісм	Collector Current-Peak	15	Α
l <sub>Β</sub>	Base Current- Continuous	0.5	Α
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	60	W
Tj	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-65~150	$^{\circ}$







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 30mA, I <sub>B</sub> = 0	80			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A ,I <sub>B</sub> = 10mA			2.0	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10A ,I <sub>B</sub> = 40mA			3.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10A ,I <sub>B</sub> = 40mA			3.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 10A ; V <sub>CE</sub> = 4V			3.0	V
I <sub>CBO</sub>	Collector Cutoff current	V <sub>CB</sub> = 80V, I <sub>E</sub> = 0			1	mA
I <sub>CEO</sub>	Collector Cutoff current	V <sub>CE</sub> = 40V, I <sub>B</sub> = 0			2	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			2	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 5A ; V <sub>CE</sub> = 4V	1000			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 10A ; V <sub>CE</sub> = 4V	500			

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